Module No	Unit No	Topics	Hrs.
1.0		Introduction of Electronic Devices	05
	1.1	Study of pn junction diode characteristics & diode current equation. Application of zener diode as a voltage regulator.	
	1.2	Construction, working and characteristics of BJT, JFET, and E-MOSFET	
2.0		Biasing Circuits of BJTs and MOSFETs	06
	2.1	Concept of DC load line, Q point and regions of operations, Analysis and design of biasing circuits for BJT (Fixed bias & Voltage divider Bias)	
	2.2	design of biasing circuits for JFET (self bias and voltage divider bias), E-MOSFET (Drain to Gate bias & voltage divider bias).	
3.0	0.4	Small Signal Amplifiers	06
	3.1	(Zi, Zo, Av and Ai) of CE amplifier using hybrid pi model.	
	3.2	Small signal analysis (Zi, Zo, Av) of CS (for EMOSFET) amplifiers.	
	3.3	Introduction to multistage amplifiers.(Concept, advantages & disadvantages)	
4.0		Frequency response of Small signal Amplifiers:	08
	4.1	Effects of coupling, bypass capacitors and parasitic capacitors on	
		frequency response of single stage amplifier, Miller effect and	
		Miller capacitance.	
	4.2	High and low frequency analysis of CE amplifier.	
	4.3	High and low frequency analysis of CS (E-MOSFET) amplifier.	
5.0		Large Signal Amplifiers:	06
	5.1	Difference between small signal & large signal amplifiers. Classification and working of Power amplifier	
	5.2	Analysis of Class A power amplifier (Series fed and transformer	
		coupled).	
	5.3	Transformer less Amplifier: Class B power amplifier. Class AB output stage with diode biasing	
	5.4	Thermal considerations and heat sinks.	
6.0		Introduction to Differential Amplifiers	08
	6.1	E-MOSFET Differential Amplifier, DC transfer characteristics,	
	. -	operation with common mode signal and differential mode signal	
	6.2	Differential and common mode gain, CMRR, differential and common mode Input impedance.	
	6.3	Two transistor (E-MOSFET) constant current source	
		Total	39